

**FEE TRANSMITTAL**

Electronic Version v08

Stylesheet Version v08.0

**Title of  
Invention**

Method for Manufacturing Buried Insulating Layer Type Single Crystal Silicon Carbide Substrate and Manufacturing Device for the Same

Application Number :

Date :

First Named Applicant: Katsutoshi IZUMI

Attorney Docket Number: 040091

**TOTAL FEE AUTHORIZED \$ 1136**

Patent fees are subject to annual revisions on or about October 1st of each year.

Filing as large entity

**BASIC FILING FEE**

Fee Description	Fee Code	Amount \$	Fee Paid \$
Utility Filing Fee	1001	770	770
Subtotal For Basic Filing Fees: \$ 770			

**EXTRA CLAIM FEES**

Fee Description	Extra Claim	Fee Code	Amount \$	Fee Paid \$
Total Claims : 22	2	1202	18	36
Independent Claims : 2	0	1201	86	0
Multiple Dependent Claims		1203	290	290
Subtotal For Extra Claims Fees: \$ 326				

**ASSIGNMENT FEES**

Fee Description	Property Number	Quantity	Fee Code	Amount \$	Fee Paid \$
Recording Each Patent Assignment Per Property Fee	00000000	1	8021	40	40
Subtotal For Additional Fees: \$40					

**AUTHORIZED BILLING INFORMATION****The commissioner is hereby authorized to charge indicated fees and credit any overpayments to:**

Deposit account number: 012340

Access Code \*\*\*\*

Deposit name: Armstrong, Kratz, Quintos, Hanson, Brooks, LLP.

Deposit authorized name: Mel R. Quintos

Signature:

/MRQ/

Date (YYYYMMDD):

2004-03-12

Charge Assignment Fees Required Under 37 C.F.R. Section 1.21 (h).